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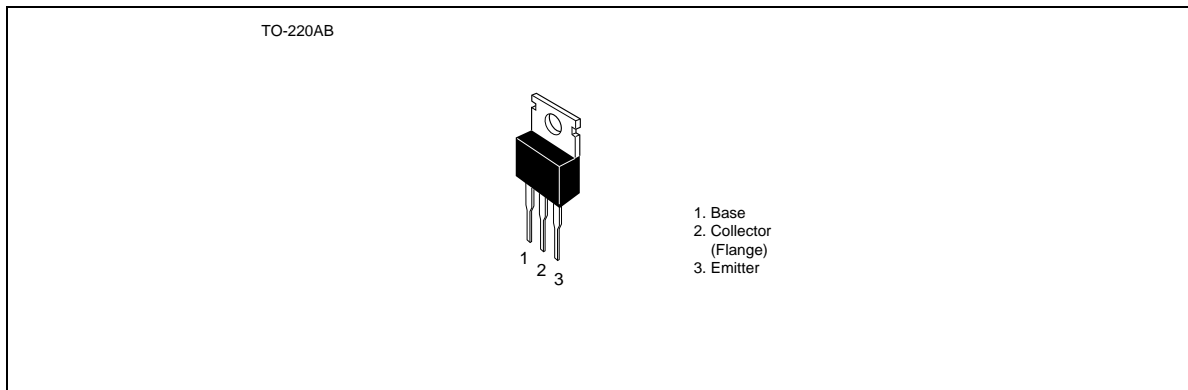
Silicon NPN Triple Diffused

HITACHI

Application

High voltage, high speed and high power switching

Outline



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	900	V
Collector to emitter voltage	V_{CEO}	800	V
Emitter to base voltage	V_{EBO}	7	V
Collector current	I_{C}	3	A
Collector peak current	$I_{\text{C(peak)}}$	6	A
Base current	I_{B}	1.5	A
Collector power dissipation	P_{C}^{*1}	40	W
Junction temperature	T_{j}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

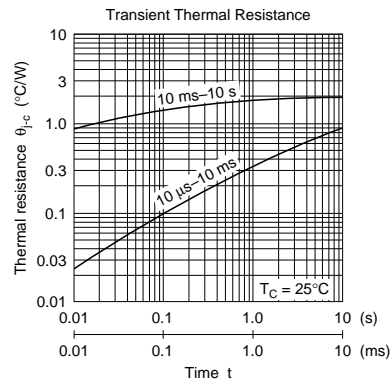
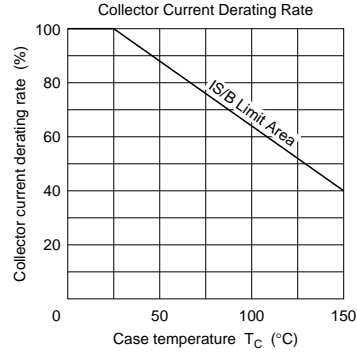
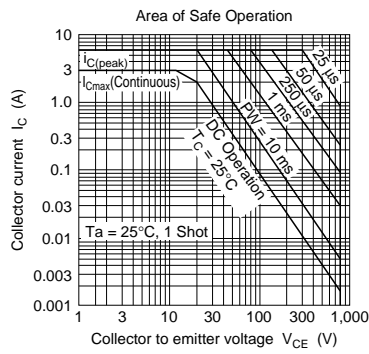
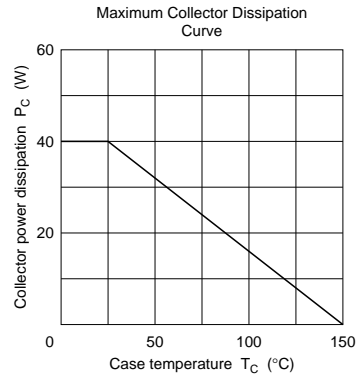
Note: 1. Value at $T_{\text{c}} = 25^\circ\text{C}$.

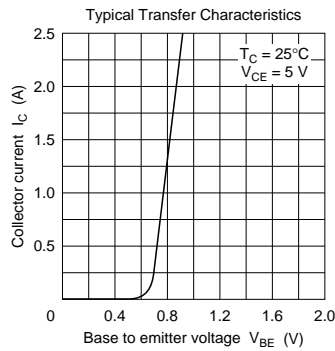
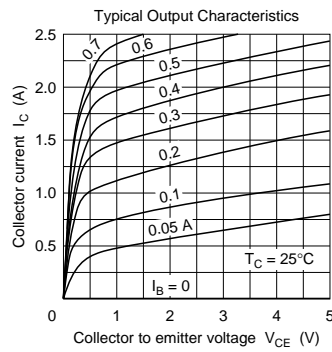
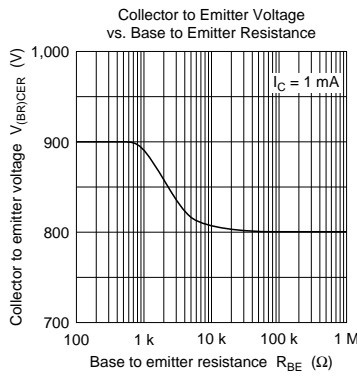
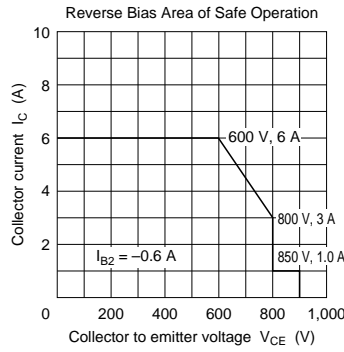
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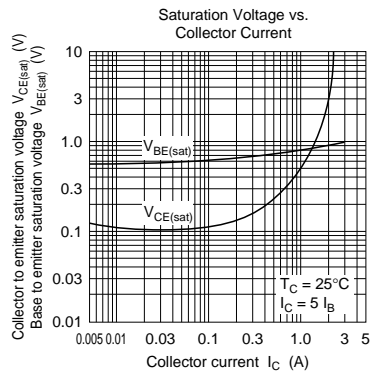
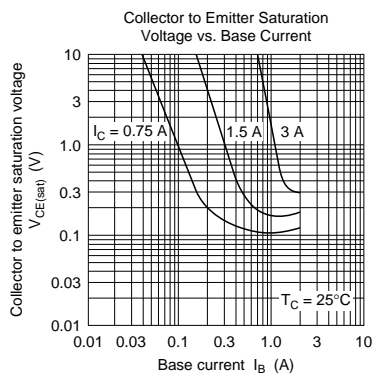
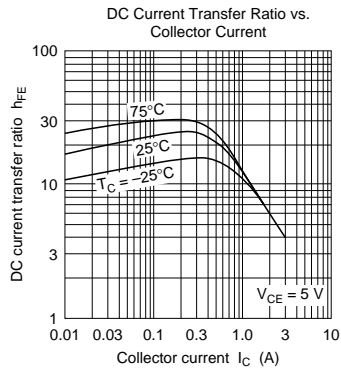
Electrical Characteristics (Ta = 25°C)

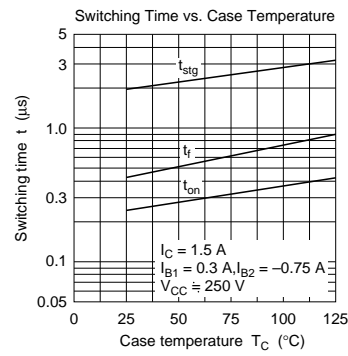
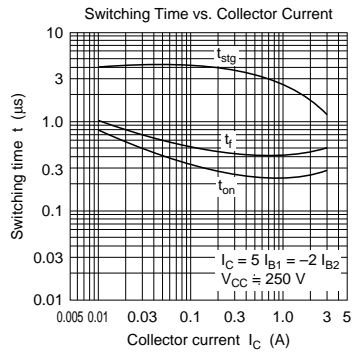
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to emitter sustain voltage	$V_{CEO(sus)}$	800	—	—	V	$I_C = 0.2 \text{ A}$, $R_{BE} = _$, $L = 100 \text{ mH}$
	$V_{CEX(sus)}$	800	—	—	V	$I_C = 3 \text{ A}$, $I_{B1} = 0.9 \text{ A}$, $I_{B2} = -0.6 \text{ A}$, $V_{BE} = -5.0 \text{ V}$, $L = 180 \text{ } \mu\text{H}$, Clamped
Emitter to base breakdown voltage	$V_{(BR)EBO}$	7	—	—	V	$I_E = 10 \text{ mA}$, $I_C = 0$
Collector cutoff current	I_{CBO}	—	—	100	μA	$V_{CB} = 750 \text{ V}$, $I_E = 0$
	I_{CEO}	—	—	100	μA	$V_{CE} = 650 \text{ V}$, $R_{BE} = _$
DC current transfer ratio	h_{FE1}	15	—	—		$V_{CE} = 5 \text{ V}$, $I_C = 0.3 \text{ A}^{*1}$
	h_{FE2}	7	—	—		$V_{CE} = 5 \text{ V}$, $I_C = 1.5 \text{ A}^{*1}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	—	1.0	V	$I_C = 0.75 \text{ A}$, $I_B = 0.15 \text{ A}^{*1}$
Base to emitter saturation voltage	$V_{BE(sat)}$	—	—	1.5	V	
Turn on time	t_{on}	—	—	1.0	μs	$I_C = 1.5 \text{ A}$, $I_{B1} = 0.3 \text{ A}$, $I_{B2} = -0.75 \text{ A}$, $V_{CC} \cong 250 \text{ V}$
Storage time	t_{stg}	—	—	3.0	μs	
Fall time	t_f	—	—	1.0	μs	

Note: 1. Pulse test









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